
HVC350B Spice parameter

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* Model generated on Sep 24, 96
* MODEL FORMAT: HITACHI SPICE
* HITACHI DIODE Model
. MODEL HVC350B ZDV D
+EG=1.1100E+00
+CJO=2.7445E-11
+TT=5.1390E-06
+CJO2=1.4335E-08
+COFF=4.1000E-12
+IS=1.4300E-15
+PB=7.7000E-01
+BV=1.5000E+01
+M2=4.9323E+00
+N=1.0265E+00
+M=6.2340E-01
+IBV=8.1334E-13
+VR1=1.0000E+00
+RS=5.0000E-01: Ohmic resistance, Unit: Ohm
+FC=5.0000E-01
+TEMP=2.5000E+01
+VR2=4.0000E+00
**** END of HVC350B (Variable capacitance diode)
*      EG: Activation energy, Unit:Ve
*      CJO: Junction capacitance, Unit:F
*      TT: Transit time, Unit: sec
*      CJO2: Junction capacitance, Unit:F
*      COFF:
*      IS: Saturation current, Unit:A
*      PB:
*      BV: Rev.breakdown voltage, Unit:V
*      M2: Geading coefficient
*      N: Emission coefficient
*      M: Geading coefficient
*      IBV: I at V-breakdown, Unit:A
*      VR1: Peak reverse voltage
*      RS: Ohmic resistance, Unit: Ohm
*      FC: Depretion cap. Coefficient
*      TEMP: Temperature
*      VR2: Peak reverse voltage
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